

MARRI LAXMAN REDDY INSTITUTE OF TECHNOLOGY AND MANAGEMEN

(Approved by AICTE, New Delhi & Affiliated to JNTUH, Hyderabad)

Accredited by NBA and NAAC with 'A' Grade & Recognized Under Section2(f) & 12(B)of the UGC act, 1956

II B.Tech I Sem Supplementary Examination, July-2022

Analog Electronics

(EEE)

Time: 3 Hours. Max. Marks: 70

Note: 1. Answer any FIVE questions.

2. Each question carries 14 marks and may have a, b as sub questions.

1	a)	Illustrate V-I characteristics of a PN-junction Diode and then explain the same.	7M	CO1	L2
	b)	Draw the Full-wave Rectifier circuit and then explain its operation with the help of waveforms.	7M	CO1	L2
2		Illustrate input and output characteristics of BJT in CB, CE and CC configurations by clearly indicating different regions.	14M	C01	L2
3	a)	Draw and explain the structure of MOSFET.	7M	CO2	L2
	b)	Explain how MOSFET can be used as a Switch.	7M	CO2	L2
4		With the help of circuit diagram, explain Common-emitter amplifier. Also, draw its small-signal equivalent circuit and then define its gain, input impedance, output impedance.	14M	CO2	L3
5	a)		9M	CO3	L2
	b)	List the advantages and disadvantages of direct coupled and RC coupled amplifiers.	5M	CO3	L2
6		Draw and explain the operation of Class-A Power amplifier circuits. Also, state advantages and disadvantages. Also, mention conduction angle, efficiency of class-A power amplifier.	14M	CO3	L3
7	a)	Explain the effect of negative feedback on amplifier	7M	CO4	L2
		characteristics. Draw and explain the RC Phase-shift oscillator circuit.	7M	CO4	L3
8		Draw and explain Op Amp based square-wave and Triangular wave generators. Also, design Integrator circuit using Op Amp.	14M	C05	L4